

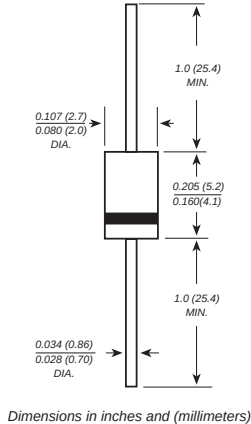


1N5817 THRU 1N5819

SCHOTTKY BARRIER RECTIFIER

Reverse Voltage - 20 to 40Volts Forward Current - 1.0 Ampere

DO-41



FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ Metal silicon junction, majority carrier conduction
- ◆ Guardring for overvoltage protection
- ◆ Low power loss, high efficiency
- ◆ High current capability, low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ High temperature soldering guaranteed:
250°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: JEDEC DO-41 molded plastic body
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight: 0.012 ounce, 0.33 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase half-wave 60Hz, resistive or inductive load, for current capacitive load derate by 20%.

MDD Catalog Number	SYMBOLS	1N5817	1N5818	1N5819	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	VOLTS
Maximum RMS voltage	V_{RMS}	14	21	28	VOLTS
Maximum DC blocking voltage	V_{DC}	20	30	40	VOLTS
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_L = 90^\circ\text{C}$	I_{AV}	1.0			Amp
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	25.0			Amps
Maximum instantaneous forward voltage at 1.0A	V_F	0.450	0.550	0.600	Volts
Maximum DC reverse current $T_A = 25^\circ\text{C}$ at rated DC blocking voltage $T_A = 100^\circ\text{C}$	I_R	0.5 10.0			mA
Typical junction capacitance (NOTE 1)	C_J	110.0			pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	50.0			$^\circ\text{C/W}$
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +125			$^\circ\text{C}$

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted



RATINGS AND CHARACTERISTIC CURVES 1N5817 THRU 1N5819

FIG. 1- FORWARD CURRENT DERATING CURVE

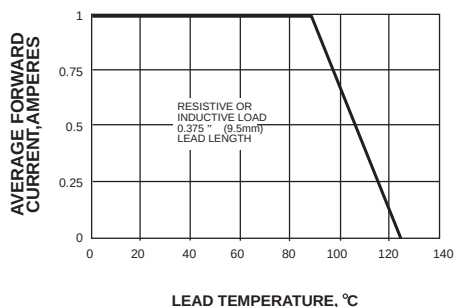


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

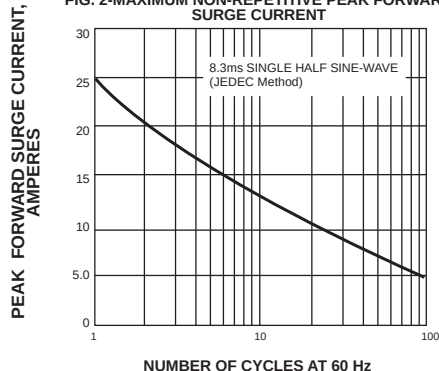


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

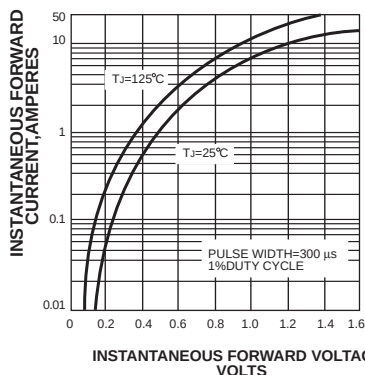


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

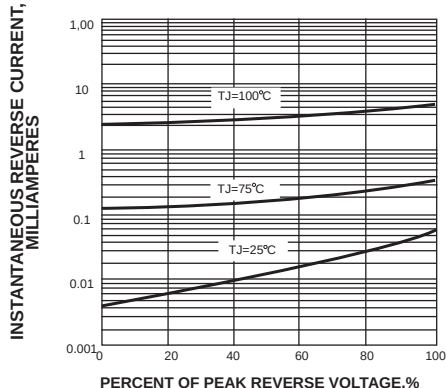


FIG. 5-TYPICAL JUNCTION CAPACITANCE

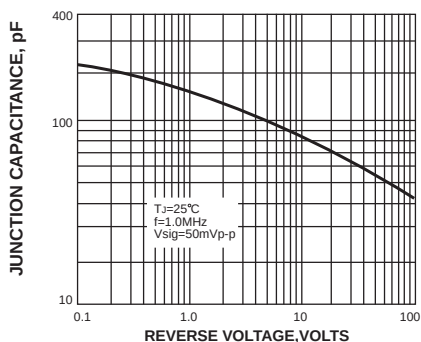
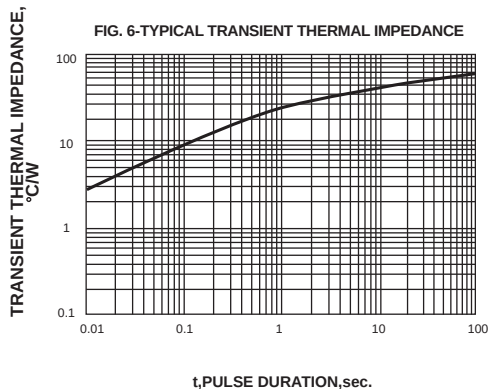


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考)!



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